

AN005 – SiC MOSFET Gate Drive Module

碳化硅MOSFET 门级驱动模块 AZ-SiC-EVB-GD

About this document

Scope and purpose

This application note provides an overview of the evaluation board AZ-SiC-EVB-GD including its main features, key specification, pin assignments and mechanical dimensions.

AZ-SiC-EVB-GD is a complete SiC gate drive board including one optocoupler, one isolated power supply, one ultra-fast gate driver IC and EMI filter. In combination with control boards or equipment that are capable of output pulse width modulation (PWM) signal, the gate drive module features and demonstrates AZ Power's SiC MOSFETs for most power electronic applications.

The evaluation board AZ-SiC-EVB-GD was developed to support customers to speed up their product development during their initial hardware design with the isolated gate driving circuits of SiC power devices. The gate drive module is designed to support very high switching frequency operation of the SiC power device.

Intended audience

This application note is intended for power electronic engineers who wants to:

1, evaluate the performance of AZ Power's SiC power devices.

2, speed up product development during initial design with existing plug and play gate driving circuits.



AZ-SiC-EVB-GD Ver 1.0

Page 1 of 15





Table of Contents

About this document	1
1.Safety Precautions	3
2.Introduction	4
3.Design features	6
3.1. Detailed Specifications of The Evaluation Board	7
3.2. Functional Groups	8
3.3. Power Interface Pin Assignment	11
3.4. Sensing for Closed-loop Control	12
4. Revision History	15

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Page 2 of 15

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1.Safety Precautions



AZ-SiC-EVB-GD Ver 1.0



2.Introduction

The AZ-SiC-EVB-GD evaluation board is designed for general SiC power device driving purpose and evaluating the performance of AZ Power's SiC power devices.

The gate drive board is intended for use with any control boards or signal generators that are capable of outputting PWM signals. This evaluation board can be easily interfaced to appropriate mother board via interface pin connectors.

This evaluation board is designed as an easy-to-use plug & play module based on ultra-fast gate driver IC. The evaluation board includes a pin connector for connecting the 12V power supply and PWM signal input, a pin connector for connecting the gate & source of the MOSFET and an EMI filter.

The AZ-SiC-EVB-GD evaluation board is available via regular AZ Power distribution partners as well as on AZ Power's website. The features of this board are described in the design feature chapter of this document. The remaining paragraphs provide information enabling customers to copy, modify and qualify the design for production according to their own specific requirements.

Environmental conditions were considered in the design of the AZ-SiC-EVB-GD. The design was tested as described in this document, but not qualified in terms of safety requirements, manufacturing and operation over the entire operating temperature range or lifetime. The boards provided by AZ Power are subject to functional testing only.

Evaluation boards are not subject to the same procedures as regular products regarding returned material analysis, process change notification and product discontinuation. Evaluation boards are intended to be used under laboratory conditions and by trained specialists only.

The block diagram of the AZ-SiC-EVB-GD is depicted in Figure 1. This evaluation board includes EMI filter, isolated DC/DC power supply, opto-coupler and ultra-fast gate driver IC. All the important control signals can be measured and observed via test points on the evaluation board. The hardware circuit relative to adjusting MOSFET turn-on/turn-off speed can be implemented through changing the resistance value of the gate resistors.

The signal circuitry of the evaluation board is fully isolated from the power circuitry by using isolated power supply and optocoupler. The design can be easily upgraded to enhance the electrical insulation by replacing the present opto-coupler and the auxiliary power supply that meets the safety requirement.







Figure 1. The block diagram of the AZ-SiC-EVB-GD evaluation board

AZ-SiC-EVB-GD Ver 1.0

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Page 5 of 15



3.Design features

AZ-SiC-EVB-GD is a plug and play board for SiC MOSFET driving purpose, which is designed to evaluate the performance of AZ Power's SiC power devices. By connecting to an appropriate mother board that has compatible interface, it demonstrates AZ Power's silicon carbide power device technology.

The features of the evaluation board:

• Enhanced creepage between the primary side signal circuitry and the secondary side power circuitry on the printed circuit board (PCB)

- Insulation between power circuitry and signal circuitry
- Isolated DC/DC power supply with 5.2kVDC isolation rating
- Opto-coupler with 5kVRMS isolation rating
- Design based on ultra-fast gate driver IC
- Different resistance value for MOSFET turn-on and turn-off
- On-board EMI filter
- Measurement test points compatible with standard oscilloscope probes
- RoHS compliant

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3.1. Detailed Specifications of The Evaluation Board

Parameters	Values	Comments
Input		
Nominal Input Voltage	12V	
Input Voltage Range	10.8 VDC ~ 13.2 VDC	
Output		
Nominal Output DC Voltage	+20 VDC / -5 VDC	
Peak Output Current – Source*	14 A	Ta=25°C
Peak Output Current – Sink*	14 A	Ta=25°C
Output Power Per Gate (Average)	2 W	
Signals		
Recommended Input Logic Level - High	5 V ~ 12 V	
Recommended Input Logic Level - Low	0 V	
Maximum Propagation Delay -	150 ns	
Low to High		
Maximum Propagation Delay -	140 ns	
High to Low	1.0.1/ .0.1	
Input Inresnoid Voltage (High)	1.2 V ~ 2V	
Input Threshold Voltage (Low)	0 V ~ 1V	
Switching Frequency		
Maximum Switching Frequency f _{max}	500 kHz	This value is MOSFET dependent
System Environment		
Ambient Temperature	From 0 to 85°C	
PCB Information		
Material	FR4	
Dimension	42.4 mm x 25 mm	

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Page 7 of 15



3.2. Functional Groups

The next two figures illustrate the functional groups on the top and bottom side of the evaluation board. And a third figure shows the side view of the evaluation board. The functional groups are explained in Table 1.



Figure 2. The top view of the AZ-SiC-EVB-GD evaluation board







Figure 3. The bottom view of the AZ-SiC-EVB-GD evaluation board



Figure 4. The side view of the AZ-SiC-EVB-GD evaluation board

AZ-SiC-EVB-GD Ver 1.0

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Page 9 of 15



Table 1. Functional Groups of The Evaluation Board

Number	Functional Group	
1	Isolated DC/DC power supply	
2	Opto-coupler with 5kVRMS isolation rating	
3	Gate drive module power indicator	
4	Gate resistors	
5	Ultra-fast gate driver IC	
6	Common mode EMI filter	
7	Decoupling capacitors for gate driver IC	
8	Decoupling capacitors for isolated power supply	

AZ-SiC-EVB-GD Ver 1.0

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Page 10 of 15



3.3. Power Interface Pin Assignment



Figure 5. The interface of the AZ-SiC-EVB-GD evaluation board

Number	Pin	Comments
1	Power_Input_VDC+	DC voltage input postive
2	Power_Input_VDC-	DC voltage input negative
3	PWM_Input+	
4	PWM_Input-	
6, 7	Gate	To MOSFET Gate
5, 8	Source	To MOSFET Source

AZ-SiC-EVB-GD Ver 1.0

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Page 11 of 15





3.4. Sensing for Closed-loop Control



Figure 6. The schematic of the AZ-SiC-EVB-GD evaluation board

AZ-SiC-EVB-GD Ver 1.0

Page 12 of 15







Figure 7. The PCB layout of the AZ-SiC-EVB-GD evaluation board



Figure 8. The top layer PCB layout of the AZ-SiC-EVB-GD evaluation board

AZ-SiC-EVB-GD Ver 1.0

0

Page 13 of 15





Figure 9. The 2nd layer PCB layout of the AZ-SiC-EVB-GD evaluation board



Figure 10. The 3rd layer PCB layout of the AZ-SiC-EVB-GD evaluation board

AZ-SiC-EVB-GD Ver 1.0

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Page 14 of 15







Figure 11. The bottom layer PCB layout of the AZ-SiC-EVB-GD evaluation board

4. Revision History

Major changes since last revision

Document version	Description of Change
1.0	Initial Version